

Abstracts

Systematic investigations on MESFETs and passive components transplanted by epitaxial lift off onto host materials with various resistivities (1997 Vol. I [MWSYM])

T. Morf, C. Biber and W. Bachtold. "Systematic investigations on MESFETs and passive components transplanted by epitaxial lift off onto host materials with various resistivities (1997 Vol. I [MWSYM])." 1997 MTT-S International Microwave Symposium Digest 1. (1997 Vol. I [MWSYM]): 145-148.

In this paper we present RF measurements on MESFETs and spiral inductors fabricated on GaAs and transplanted by epitaxial lift off (ELO). ELO is a technology by which epitaxially grown layers are lifted off from their growth substrate and are subsequently reattached to a new host substrate.

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